

## SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 30 to 100Volts  
FORWARD CURRENT - 8.0 Amperes

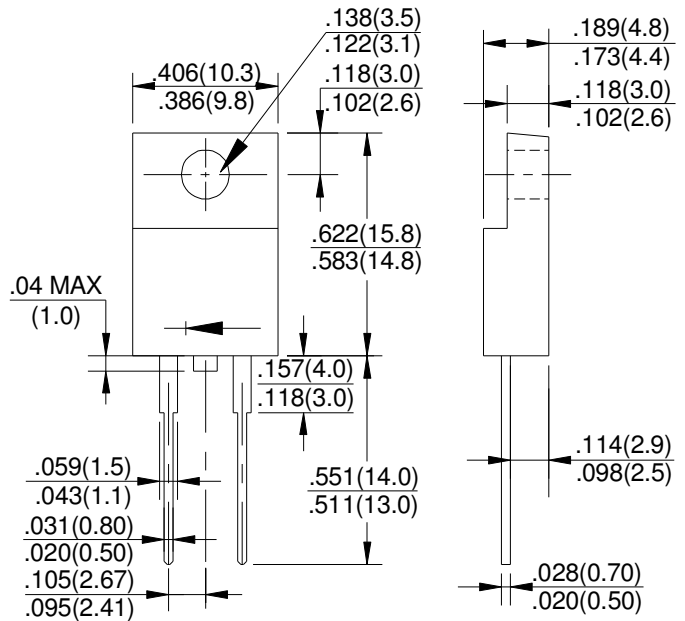
### FEATURES

- Metal of silicon rectifier , majority carrier conduction
- Guard ring for transient protection
- Low power loss,high efficiency
- High current capability,low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage,high frequency inverters,free wheeling,and polarity protection applications

### MECHANICAL DATA

- Case: ITO-220AC molded plastic
- Polarity: As marked on the body
- Weight: 0.08ounces,2.24 grams
- Mounting position :Any

### ITO-220AC



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	MBRF830	MBRF840	MBRF850	MBRF860	MBRF880	MBRF8100	UNIT
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	30	40	50	60	80	100	V
Maximum RMS Voltage	V <sub>RMS</sub>	21	28	35	42	56	70	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current ( See Fig.1)	I <sub>(AV)</sub>	8.0						A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	150						A
Peak Forward Voltage (Note1)	V <sub>F</sub>	IF=8A @T <sub>J</sub> =25°C 0.70		0.80		0.85		V
		IF=8A @T <sub>J</sub> =125°C 0.57		0.70		0.75		
		IF=16A @T <sub>J</sub> =25°C 0.84		0.95		0.95		
		IF=16A @T <sub>J</sub> =125°C 0.72		0.85		0.85		
Maximum DC Reverse Current at Rated DC Blocking Voltage	I <sub>R</sub>	@T <sub>J</sub> =25°C 0.1		15		@T <sub>J</sub> =125°C 0.1		mA
Typical Junction Capacitance (Note2)	C <sub>J</sub>	250				280		pF
Typical Thermal Resistance (Note3)	R <sub>θJC</sub>	3.0				2.0		°C/W
Operating Temperature Range	T <sub>J</sub>	-55 to +150						°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +175						°C

NOTES:1.300us pulse width,2% duty cycle.

2.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

3.Thermal resistance junction to case.

**RATING AND CHARACTERISTIC CURVES**  
**MBRF830 thru MBRF8100**



FIG. 1 – FORWARD CURRENT DERATING CURVE

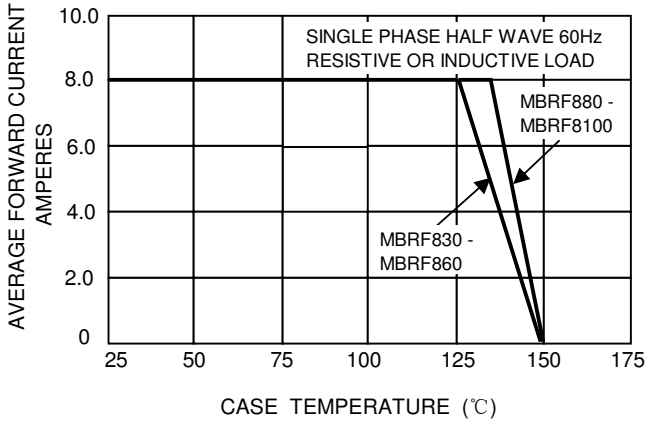


FIG. 2 – MAXIMUM NON-REPETITIVE SURGE CURRENT

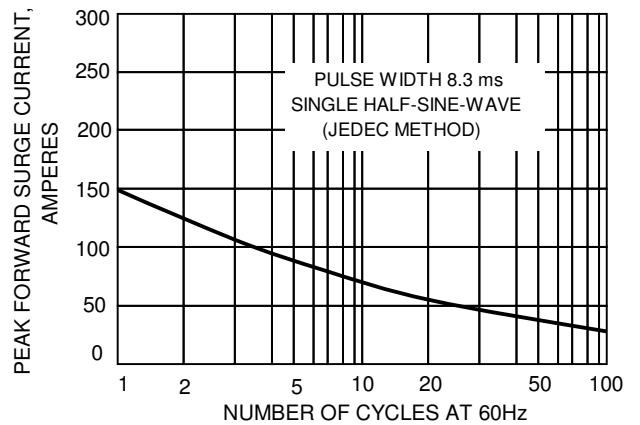


FIG.3-TYPICAL REVER CHARACTERISTICS

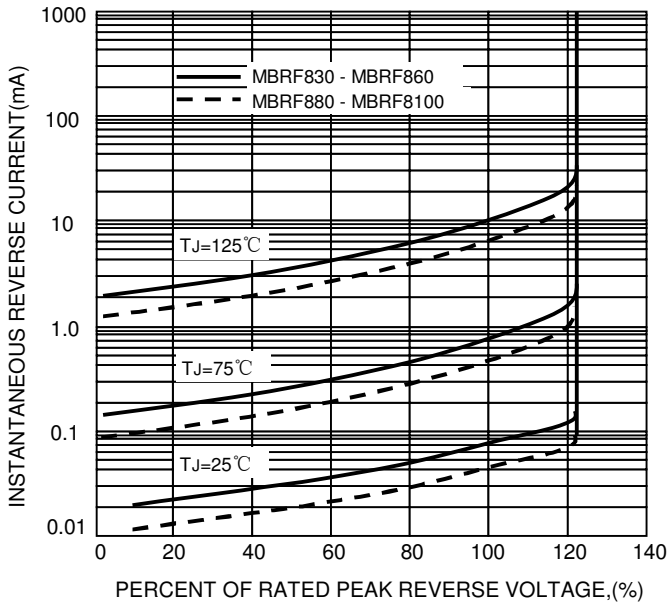


FIG.4-TYPICAL FORWARD CHARACTERISTICS

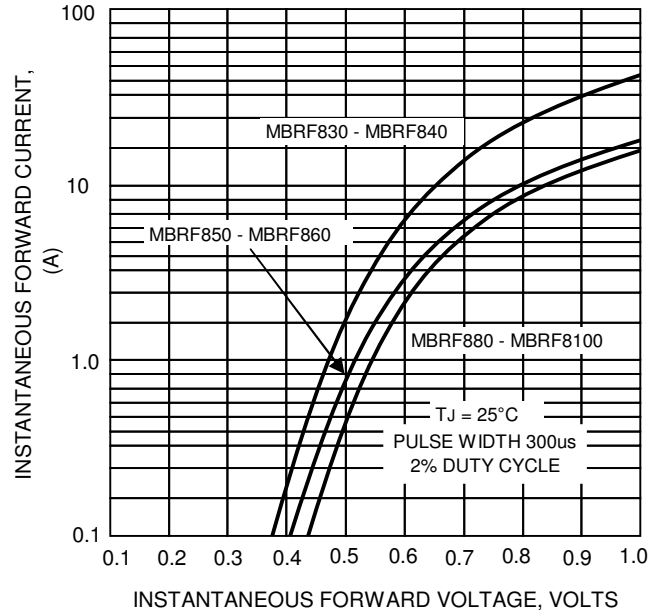


FIG.5 – TYPICAL JUNCTION CAPACITANCE

